

Final Product/Process Change Notification Document #: FPCN22366X

Document #: FPCN223662 Issue Date: 19 July 2018

Title of Change:	60V Trench 8 Technology Capacity Expansion by Qualification of Aizu Fujitsu Semiconductor Manufacturing (AFSM), Japan.			
Proposed first ship date:	31 October 2018			
Contact information:	Contact your local ON Semiconductor Sales Office or < <u>jennie.shen@onsemi.com></u>			
Samples:	Contact your local ON Semiconductor Sales Office or < PCN.samples@onsemi.com Sample requests are to be submitted no later than 30 days from the date of first notification, Initial PCN or Final PCN, for this change.			
Additional Reliability Data:	Contact your local ON Semiconductor Sales Office or < <u>Robert.Baran@onsemi.com</u> >			
Type of notification:	This is a Final Product/Process Change Notification (FPCN) sentto customers. FPCNs are issued 90 days prior to implementation of the change. ON Semiconductor will consider this change accepted, unless an inquiry is made in writing within 30 days of delivery of this notice. To do so, contact < PCN.Support@onsemi.com>			
Change Part Identification:	NTMFS5H600NLT1G; NTMFS5H600NLT3G			
Change Category:	✓ Wafer Fab Change ✓ Assembly Change ✓ Test Change ✓ Other			
Change Sub-Category(s): ✓ Manufacturing Site Add ✓ Manufacturing Site Tran ✓ Manufacturing Process	sfer Product specific change Shipping/Packaging/Marking			
Sites Affected:	ON Semiconductor Sites: External Foundry/Subcon Sites: Aizu Fujitsu Semiconductor Manufacturing			
Description and Purpose:				
This is a final change notification to customers on the qualification of additional wafer fabrication capacity of 60V Trench 8 Technology in				

This is a final change notification to customers on the qualification of additional wafer fabrication capacity of 60V Trench 8 Technology in Aizu Fujitsu Semiconductor Manufacturing (ASFM), Japan to support customer needs. There are no product material changes as a result of this change. There is no product marking change.

Reliability Data Summary:

QV Name: NVMFS5H600NLT1G

Test	Specification	Condition	Interval	Results
HTRB	JESD22-A108	Ta=175°C, 100% max rated V	2016 hrs	0/231
HTGB	JESD22-A108	Ta=175°C, 100% max rated Vgss	2016 hrs	0/231
HTSL	JESD22-A103	Ta= 175°C	2016 hrs	0/231
IOL	MIL-STD-750 (M1037) AEC-Q101	Ta=+25°C, delta Tj=100°C On/off = 2 min	30К сус	0/231
TC	JESD22-A104	Ta= -65°C to +150°C	2000 cyc	0/231
HAST	JESD22-A110	130°C, 85% RH, 18.8psig, bias	192 hrs	0/231
uHAST	JESD22-A118	130°C, 85% RH, 18.8psig, unbiased	192 hrs	0/231
PC	J-STD-020 JESD- A113	MSL 1 @ 260 °C		
RSH	JESD22- B106	Ta = 265C, 10 sec		0/90
SD	JSTD002	Ta = 245C, 10 sec		0/30

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Electrical Characteristic Summary:				
New fab qual lots meet datasheet requirement.				
List of Affected Parts:				
Part Number	Qualification Vehicle			
NTMFS5H600NLT1G	NVMFS5H600NLT1G			
NTMFS5H600NLT3G	IAA IAH 22U000IAFI TA			

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